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March 2014

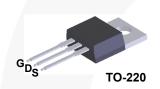
FCP11N60/FCPF11N60

General Description

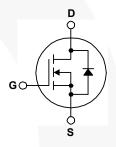
SuperFET® MOSFET is Fairchild Semiconductor's first genera-tion of high voltage super-junction (SJ) MOSFET family that is utilizing charge balance technology for outstanding low on-resistance and lower gate charge performance. This technology is tailored to minimize conduction loss, provide superior switch-ing performance, dv/dt rate and higher avalanche energy. Con-sequently, SuperFET MOSFET is very suitable for the switching power applications such as PFC, server/telecom power, FPD TV power, ATX power and industrial power applications.

Features

- 650V @T_i = 150°C
- Typ. Rds(on)=0.32Ω
- Ultra low gate charge (typ. Qg=40nC)
- · Low effective output capacitance (typ. Coss.eff=95pF)
- · 100% avalanche tested
- RoHS Compliant







Absolute Maximum Ratings T_C = 25°C unless otherwise noted

Symbol	Parameter	FCP11N60 FCPF11N60		Units	
I _D	Drain Current - Continuous (T _C = 25°C)		11	11*	Α
	- Continuous (T _C = 100°C)		7	7*	Α
I _{DM}	Drain Current - Pulsed	(Note 1)	33	33*	Α
V _{GSS}	Gate-Source Voltage		± 30		V
E _{AS}	Single Pulsed Avalanche Energy	(Note 2)	340		mJ
I _{AR}	Avalanche Current	(Note 1)	11		Α
E _{AR}	Repetitive Avalanche Energy	(Note 1)	12.5		mJ
dv/dt	Peak Diode Recovery dv/dt (Note 3)		4.5		V/ns
P_{D}	Power Dissipation (T _C = 25°C)		125	36	W
	- Derate above 25°C		1.0	0.29	W/°C
T _J , T _{STG}	Operating and Storage Temperature Range		-55 to +150		°C
T _L	Maximum lead temperature for soldering purp 1/8" from case for 5 seconds	300		°C	

^{*} Drain current limited by maximum junction termperature

Thermal Characteristics

Symbol	Parameter	FCP11N60	FCPF11N60	Units
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case	1.0	3.5	°C/W
$R_{\theta CS}$	Thermal Resistance, Case-to-Sink	0.5		°C/W
$R_{\theta JA}$	A Thermal Resistance, Junction-to-Ambient		62.5	°C/W

Package Marking and Ordering Information

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FCP11N60	FCP11N60	TO-220	Tube	N/A	N/A	50 units
FCPF11N60	FCPF11N60	TO-220F	Tube	N/A	N/A	50 units
FCPF11N60T	FCPF11N60T	TO-220F	Tube	N/A	N/A	50 units

Electrical Characteristics

 T_C = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Cha	aracteristics					
BV _{DSS} Drain-Source Breakdown Voltage		$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}, T_A = 25^{\circ}\text{C}$				V
		V _{GS} = 0 V, I _D = 250 μA, T _J = 150°C		650		V
ΔBV _{DSS} / ΔT _J	Breakdown Voltage Temperature Coefficient	I _D = 250 μA, Referenced to 25°C		0.6		V/°C
BV _{DS}	Drain-Source Avalanche Breakdown Voltage	V _{GS} = 0 V, I _D = 11 A		700		V
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 600 V, V _{GS} = 0 V		1	1	μΑ
		V _{DS} = 480 V, T _C = 125°C		-	10	μΑ
I _{GSSF}	Gate-Body Leakage Current, Forward	V _{GS} = 30 V, V _{DS} = 0 V		^	100	nA
I _{GSSR}	Gate-Body Leakage Current, Reverse	$V_{GS} = -30 \text{ V}, V_{DS} = 0 \text{ V}$	-	-	-100	nA
On Cha	racteristics					
V _{GS(th)}	Gate Threshold Voltage	V _{DS} = V _{GS} , I _D = 250 μA	3.0		5.0	V
R _{DS(on)}	Static Drain-Source On-Resistance	V _{GS} = 10 V, I _D = 5.5 A		0.32	0.38	Ω
9 _{FS}	Forward Transconductance	V _{DS} = 40 V, I _D = 5.5 A (Note 4)		9.7		S
Dynami	ic Characteristics					
C _{iss}	Input Capacitance	V _{DS} = 25 V, V _{GS} = 0 V, f = 1.0 MHz		1148	1490	pF
Coss	Output Capacitance			671	870	pF
C _{rss}	Reverse Transfer Capacitance			63	82	pF
C _{oss}	Output Capacitance	V _{DS} = 480 V, V _{GS} = 0 V, f = 1.0 MHz		35		pF
C _{oss} eff.	Effective Output Capacitance	V _{DS} = 0V to 480 V, V _{GS} = 0 V		95		pF
Switchi	ing Characteristics					
t _{d(on)}	Turn-On Delay Time	V = 200 V I = 44 A		34	80	ns
t _r	Turn-On Rise Time	$V_{DD} = 300 \text{ V}, I_D = 11 \text{ A},$		98	205	ns
t _{d(off)}	Turn-Off Delay Time	$R_G = 25 \Omega$		119	250	ns
t _f	Turn-Off Fall Time	(Note 4, 5)		56	120	ns
Q _g	Total Gate Charge	V _{DS} = 480 V, I _D = 11 A,		40	52	nC
Q _{gs}	Gate-Source Charge	$V_{GS} = 10 \text{ V}$ (Note 4, 5)		7.2		nC
Q _{gd}	Gate-Drain Charge			21	\ \	nC
	ource Diode Characteristics an	nd Maximum Patings				
I _S	Maximum Continuous Drain-Source Dio				11	Α
I _{SM}	Maximum Pulsed Drain-Source Diode Forward Current			-	33	A
V _{SD}	Drain-Source Diode Forward Voltage	$V_{GS} = 0 \text{ V, } I_S = 11 \text{ A}$,,

Q_{rr}

- Notes: 1. Repetitive Rating : Pulse width limited by maximum junction temperature 2. $I_{AS} = 5.5A$, $V_{DD} = 50V$, $R_G = 25 \Omega$, Starting $T_J = 25^{\circ}C$ 3. $I_{SD} \le 11A$, $di/dt \le 200A/\mu s$, $V_{DD} \le BV_{DSS}$, Starting $T_J = 25^{\circ}C$ 4. Pulse Test : Pulse width $\le 300\mu s$, Duty cycle $\le 2\%$ 5. Essentially independent of operating temperature

Reverse Recovery Time

Reverse Recovery Charge

 $V_{GS} = 0 V, I_S = 11 A,$

 $dI_F / dt = 100 A/\mu s$

ns

μС

390

(Note 4)

Typical Characteristics

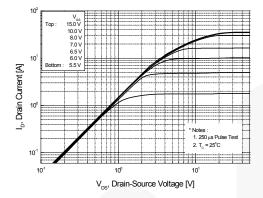


Figure 1. On-Region Characteristics

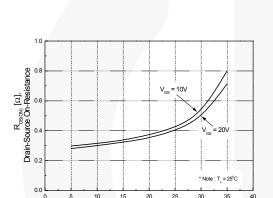


Figure 3. On-Resistance Variation vs. Drain Current and Gate Voltage

I_D, Drain Current [A]

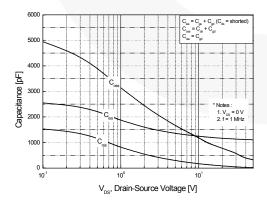


Figure 5. Capacitance Characteristics

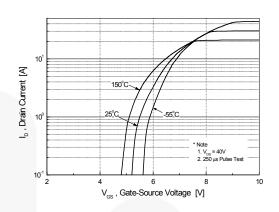


Figure 2. Transfer Characteristics

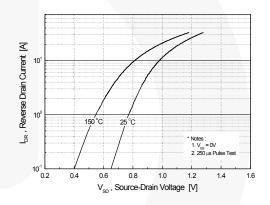


Figure 4. Body Diode Forward Voltage Variation vs. Source Current and Temperature

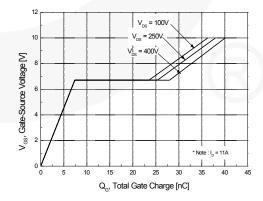


Figure 6. Gate Charge Characteristics

Typical Characteristics (Continued)

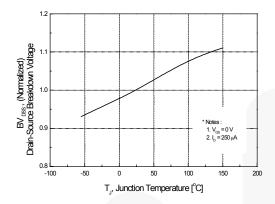


Figure 7. Breakdown Voltage Variation vs. Temperature

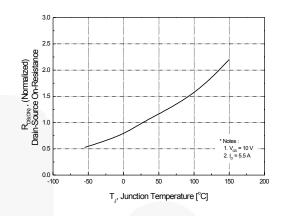


Figure 8. On-Resistance Variation vs. Temperature

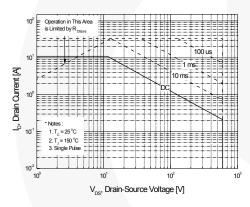


Figure 9-1. Maximum Safe Operating Area for FCP11N60

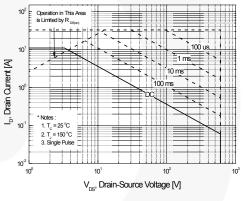


Figure 9-2. Maximum Safe Operating Area for FCPF11N60

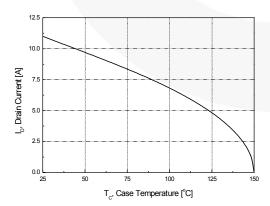


Figure 10. Maximum Drain Current vs. Case Temperature

Typical Characteristics (Continued)

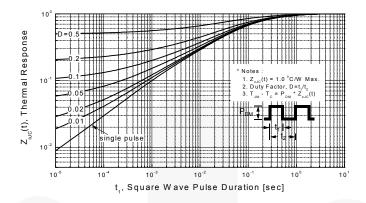


Figure 11-1. Transient Thermal Response Curve for FCP11N60

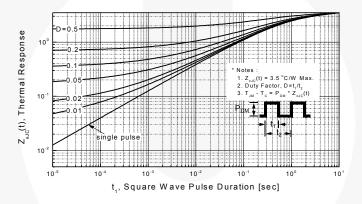


Figure 11-2. Transient Thermal Response Curve for FCPF11N60



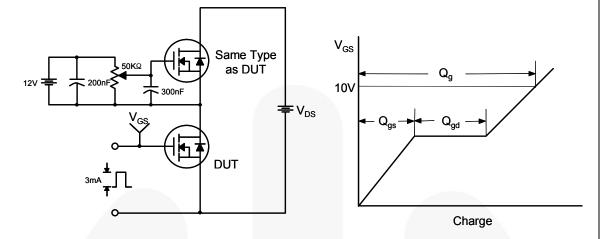


Figure 13. Resistive Switching Test Circuit & Waveforms

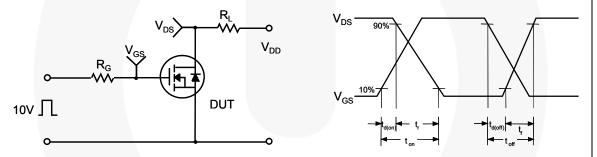
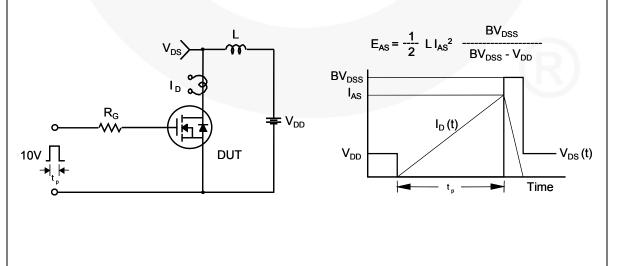
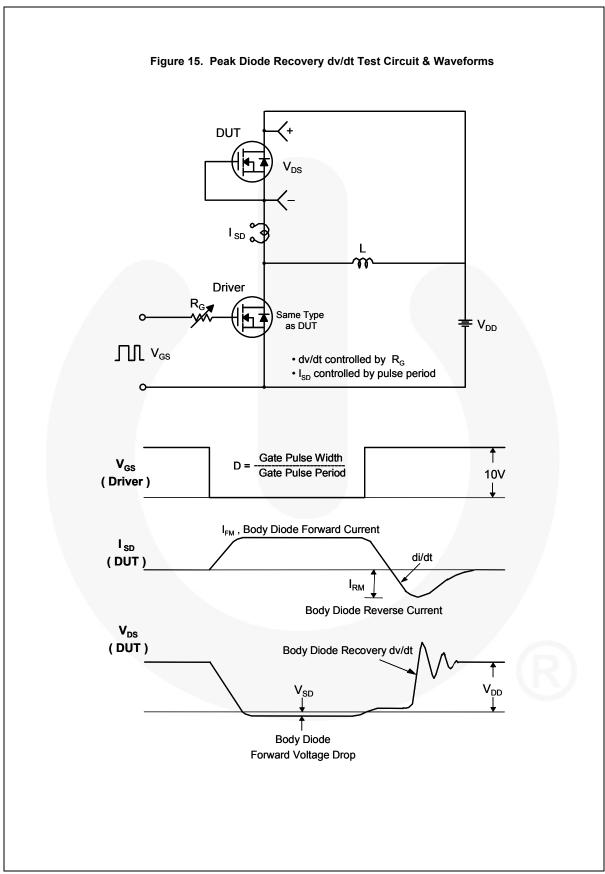


Figure 14. Unclamped Inductive Switching Test Circuit & Waveforms





Mechanical Dimensions

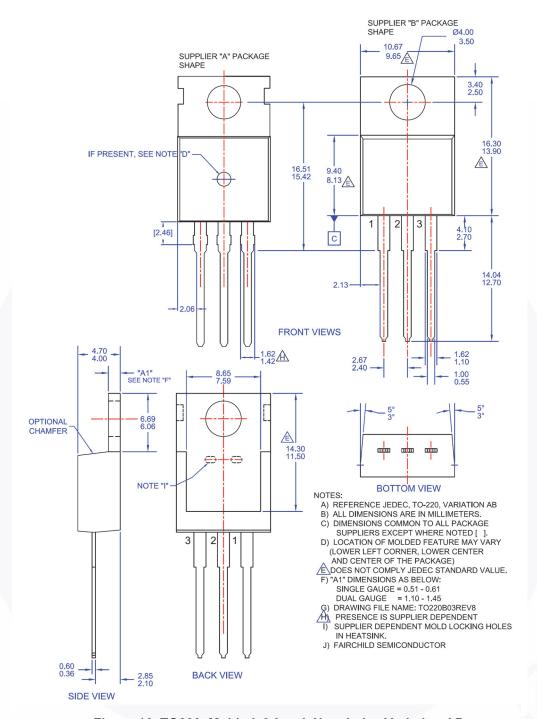


Figure 16. TO220, Molded, 3-Lead, Non Jedec Variation AB

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Mechanical Dimensions

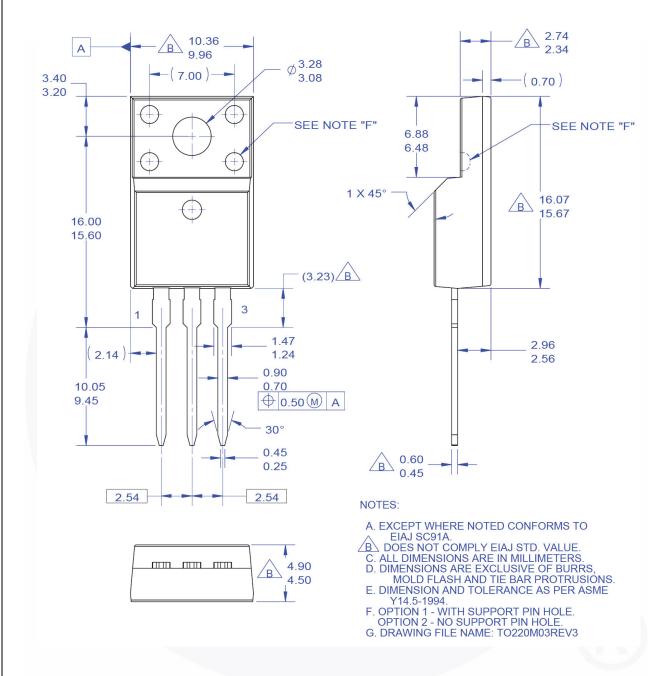


Figure 17. TO220, Molded, 3-Lead, Full Pack, EIAJ SC91, Straight Lead

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